

RJH65T14DPQ-A0

650V - 50A - IGBT

Application: Induction Heating

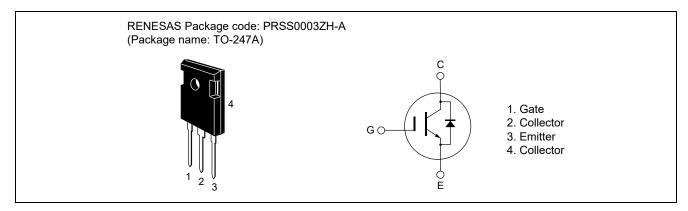
Microwave Oven

R07DS1256EJ0110 Rev.1.10 Aug 31, 2018

Features

- Optimized for current resonance application
- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.45$ V typ. (at $I_C = 50$ A, $V_{GE} = 15$ V, Ta = 25 °C)
- Built in fast recovery diode in one package
- Trench gate and thin wafer technology

Outline



Absolute Maximum Ratings

 $(Tc = 25 \, ^{\circ}C)$

Item		Symbol	Ratings	Unit
Collector to emitter voltage		V _{CES}	650	V
Gate to emitter voltage		V _{GES}	±30	V
Collector current	Tc = 25 °C	I _C Note1	100	Α
	Tc = 100 °C	Ic Note1	50	Α
Collector peak current		ic(peak) Note1	180	Α
Collector to emitter diode	Tc = 25 °C	I _{DF}	40	Α
Forward current	Tc = 100 °C	I _{DF}	20	Α
Collector to emitter diode forward peak current		i _{DF} (peak) Note2	100	Α
Collector dissipation		Pc	250	W
Junction to case thermal impedance (IGBT)		θj-c ^{Note3}	0.6	°C/W
Junction to case thermal impedance (Diode)		θj-cd ^{Note3}	1.33	°C/W
Junction temperature		Tj Note4	175	°C
Storage temperature		Tstg	-55 to +150	°C

Note: Continuous heavy condition (e.g. high temperature/voltage/current or high variation of temperature) may affect a reliability even if it are within the absolute maximum ratings. Please consider derating condition for appropriate reliability in reference Renesas Semiconductor Reliability Handbook (Recommendation for Handling and Usage of Semiconductor Devices) and individual reliability data.

Electrical Characteristics

 $(Tc = 25 \, ^{\circ}C)$

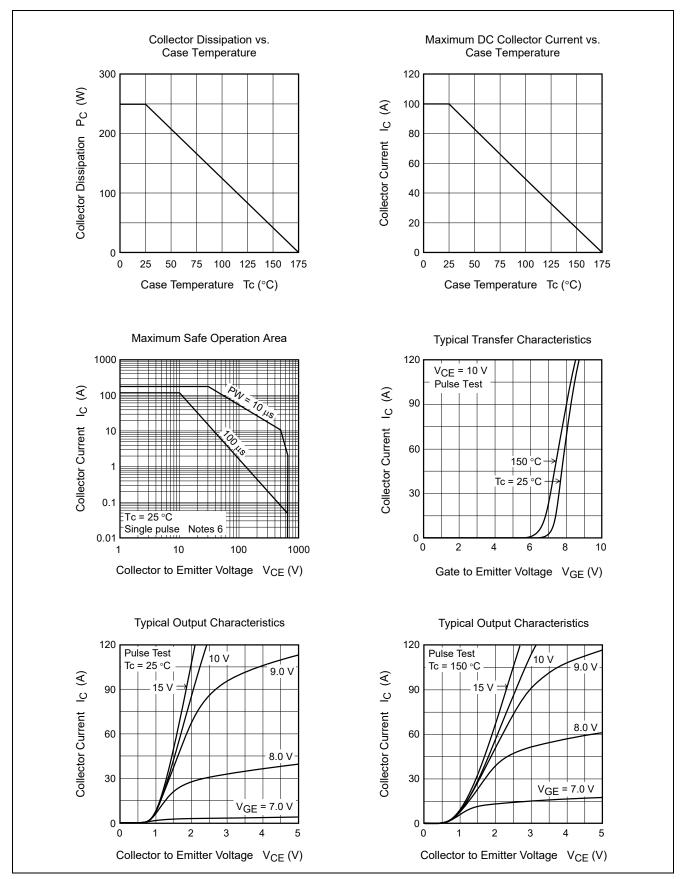
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Zero gate voltage collector current	Ices	_	_	100	μΑ	V _{CE} = 650 V, V _{GE} = 0 V
Gate to emitter leak current	I _{GES}	_	_	±1	μΑ	V _{GE} = ±30 V, V _{CE} = 0 V
Gate to emitter cutoff voltage	V _{GE(off)}	4	_	7	V	V _{CE} = 10 V, I _C = 1 mA
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.45	1.75	V	$I_C = 50 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note5}}$
Input capacitance	Cies	_	1750	_	pF	V _{CE} = 25 V
Output capacitance	Coes	_	69	_	pF	V _{GE} = 0 V
Reveres transfer capacitance	Cres	_	34	_	pF	f = 1 MHz
Total gate charge	Qg	_	80	_	nC	V _{GE} = 15 V
Gate to emitter charge	Qge	_	15	_	nC	V _{CE} = 300 V
Gate to collector charge	Qgc	_	35	_	nC	Ic = 50 A
Turn-on delay time	t _{d(on)}	_	38	_	ns	V _{CC} = 400 V
Rise time	tr	_	30	_	ns	V_{GE} = 15 V I_{C} = 50 A Rg = 10 Ω
Turn-off delay time	t _{d(off)}	_	125	_	ns	
Fall time	t _f	_	115	_	ns	
Turn-on loss energy	Eon	_	1.3	_	mJ	T _C = 25 °C
Turn-off loss energy	Eoff	_	1.2	_	mJ	Inductive load
Total switching energy	E _{total}	_	2.5	_	mJ	
Turn-on delay time	t _{d(on)}	_	38	_	ns	V _{CC} = 400 V
Rise time	tr	_	30	_	ns	V _{GE} = 15 V
Turn-off delay time	t _{d(off)}	_	130	_	ns	Ic = 50 A
Fall time	t _f	_	135	_	ns	Rg = 10 Ω
Turn-on loss energy	Eon	_	1.45	_	mJ	T _C = 150 °C
Turn-off loss energy	Eoff	_	1.45	_	mJ	Inductive load
Total switching energy	E _{total}	_	2.90	_	mJ	
Tail loss	E _{tail}	_	560	_	μJ	V_{CC} = 300 V, V_{GE} = 20 V I_{C} = 50 A, Rg = 15 Ω T_{C} = 125 °C Current resonance circuit
C-E diode forward voltage	V _{ECF}	_	1.2	1.6	V	I _F = 20 A ^{Note5}

C-E diode forward voltage	V_{ECF}	_	1.2	1.6	V	I _F = 20 A ^{Note5}
C-E diode reverse recovery time	t _{rr}	_	250	_	ns	I _F = 20 A
						$di_F/dt = -300 A/\mu s$

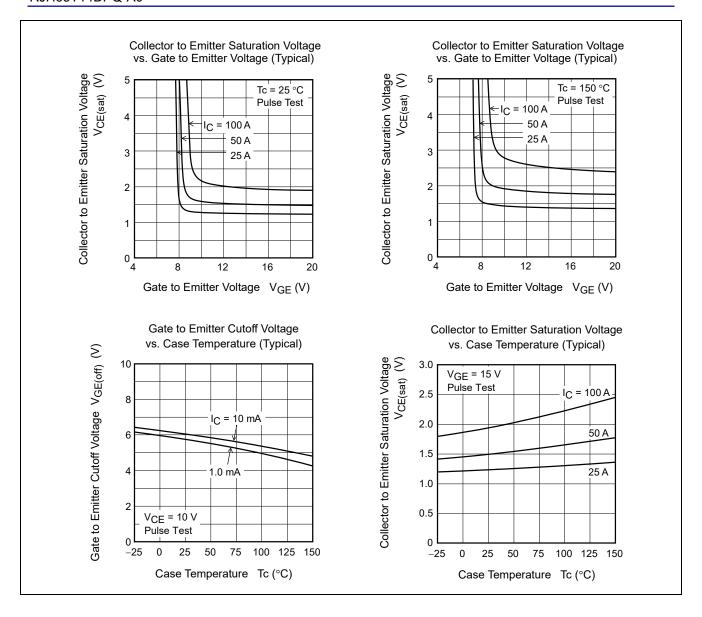
Notes: 1. Pulse width limited by safe operating area.

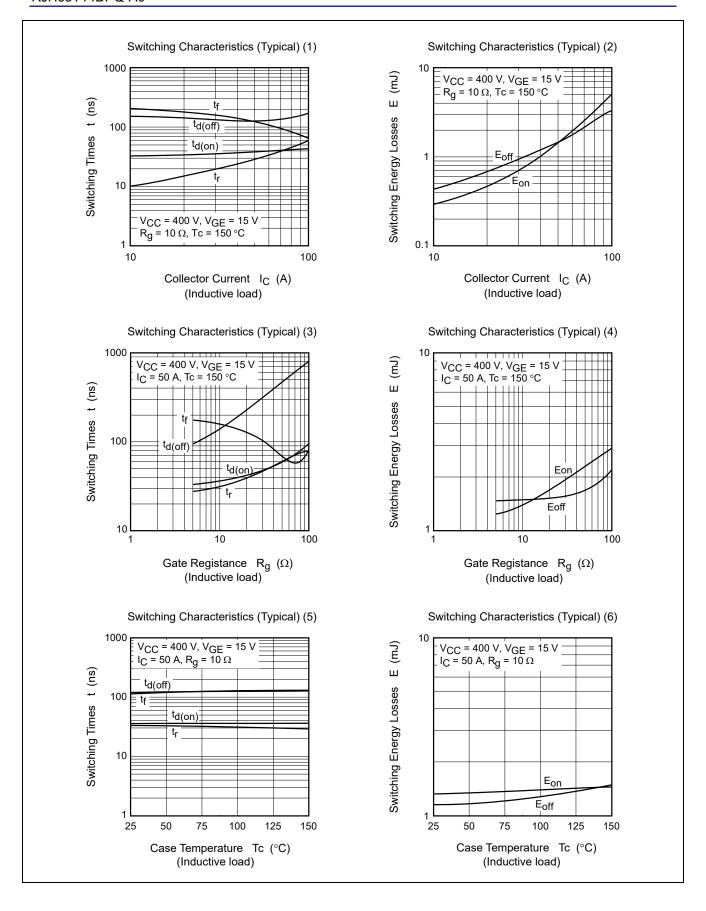
- 2. $PW \le 5 \mu s$, duty cycle $\le 1\%$
- 3. Value at Tc = 25 °C
- 4. Please use this device in the thermal conditions which the junction temperature does not exceed 175 °C. Renesas IGBT Application Note is disclosed about reliability test and application condition up to 175 °C.
- 5. Pulse test

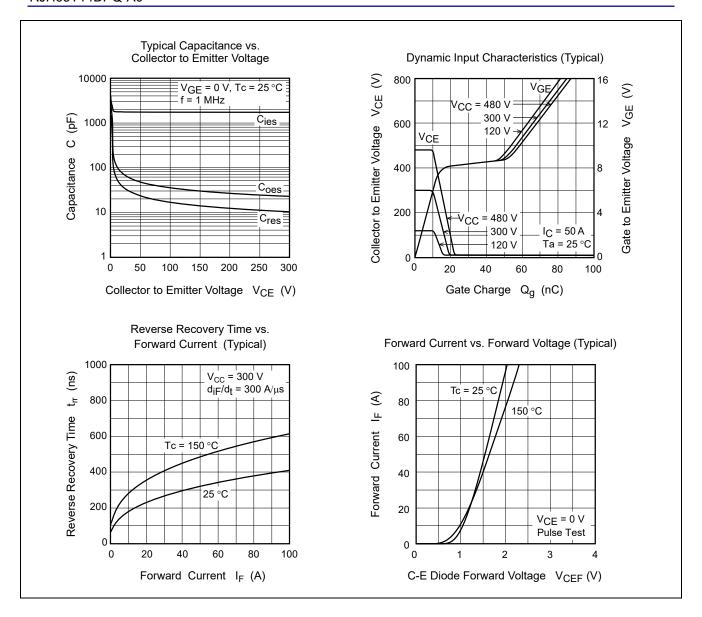
Main Characteristics

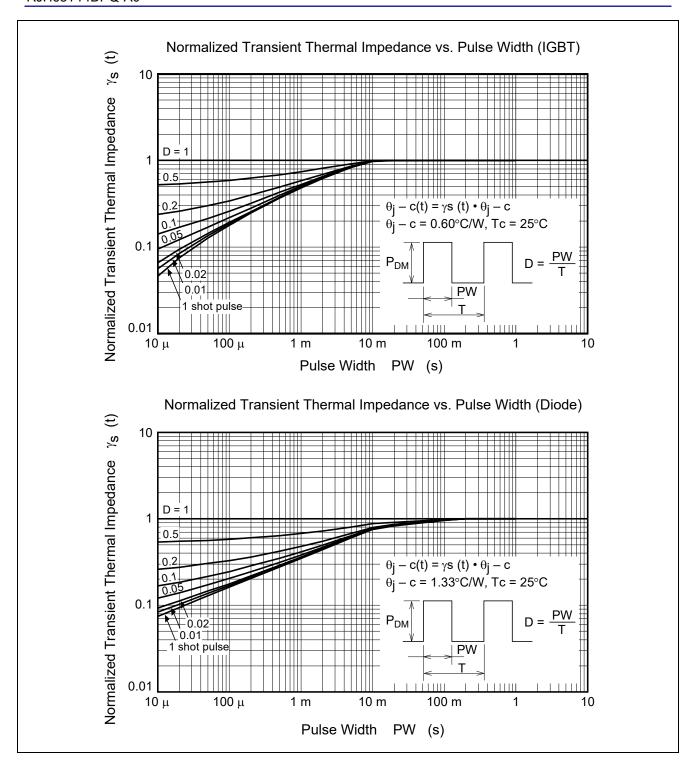


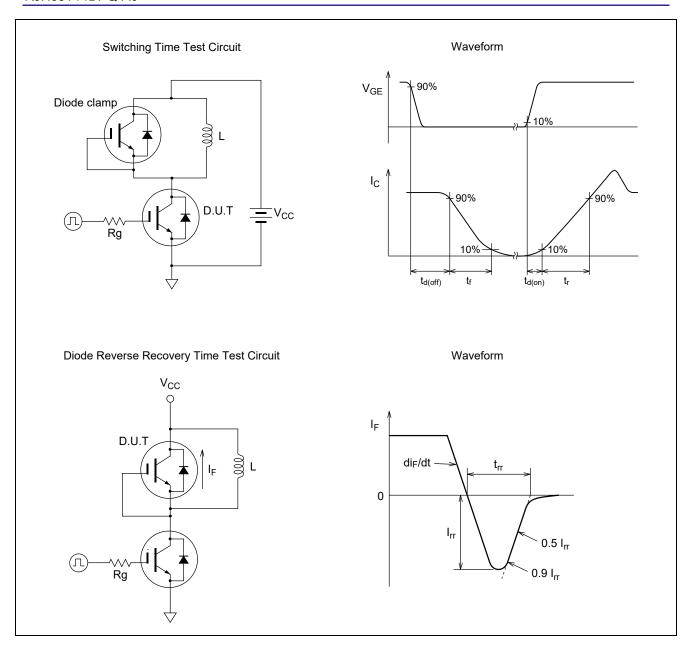
Notes: 6. This data is the designed value on Renesas's measurement condition, Renesas recommends that operating conditions are designed according to a document "Power MOSFET/IGBT Attention of Handling Semiconductor Devices (R07ZZ0010)".





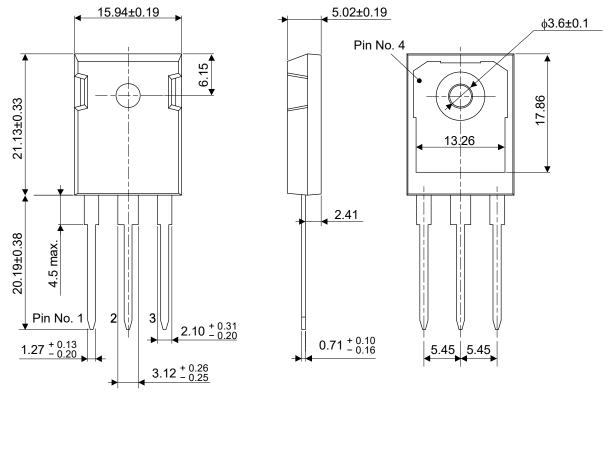






Package Dimensions

RENESAS Code	Previous Code	MASS (Typ) [g]
PRSS0003ZH-A	_	6.14
		Unit: mm



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH65T14DPQ-A0#T0	240 pcs	Box (Tube)

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Renesas Electronics America Inc.

| Murphy Ranch Road, Milpitas, CA 95035, U.S.A. +1-408-432-8888, Fax: +1-408-434-5351

Renesas Electronics Canada Limited 9251 Yonge Street, Suite 8309 Richmond Hill, Ontario Canada L4C 9T3 Tel: +1-905-237-2004

Renesas Electronics Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K
Tel: +44-1628-651-700, Fax: +44-1628-651-804

Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germar Tel: +49-211-6503-0, Fax: +49-211-6503-132

Renesas Electronics (China) Co., Ltd.
Room 1709 Quantum Plaza, No.27 ZhichunLu, Haidian District, Beijing, 100191 P. R. China Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd. Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai, 200333 P. R. China Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

Renesas Electronics Hong Kong Limited
Unit 1601-1611, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong Tel: +852-2265-6688, Fax: +852 2886-9022

Renesas Electronics Taiwan Co., Ltd.

13F, No. 363, Fu Shing North Road, Taipei 10543, Taiwan Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

Renesas Electronics Singapore Pte. Ltd.
80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre, Singapore 339949 Tel: +65-6213-0200, Fax: +65-6213-0300

Renesas Electronics Malaysia Sdn.Bhd.
Unit 1207, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

Renesas Electronics India Pvt. Ltd. No.777C, 100 Feet Road, HAL 2nd St

No.777C, 100 Feet Road, HAL 2nd Stage, Indiranagar, Bangalore 560 038, India Tel: +91-80-67208700, Fax: +91-80-67208777

Renesas Electronics Korea Co., Ltd. 17F, KAMCO Yangjae Tower, 262, Gangnam-daero, Gangnam-gu, Seoul, 06265 Korea Tel: +82-2-558-3737, Fax: +82-2-558-5338